



Cite this: *J. Mater. Chem. C*, 2018, **6**, 4326

DOI: 10.1039/c8tc90056f

rsc.li/materials-c

Correction: Electronic and transport properties of Li-doped NiO epitaxial thin films

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Correction for 'Electronic and transport properties of Li-doped NiO epitaxial thin films' by J. Y. Zhang *et al.*, *J. Mater. Chem. C*, 2018, **6**, 2275–2282.

The authors regret the omission of an acknowledgement of funder support, and would like to add the following sentence to the acknowledgements section.

“Transport measurements performed by L. W. and Y. D. were supported by the Early Career Research Program through the U.S. Department of Energy, Office of Basic Energy Sciences.”

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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